| List of Figures | IV-V |
|---|-------|
| List of Tables | |
| | |
| Chapter 1 | 1-12 |
| Introduction | |
| 1.1 Introduction | 1 |
| 1.2 Thin films | 2 |
| 1.3 Dye sensitized solar cells (DSSCs) | 4 |
| 1.3.1 Details of architecture of Dye sensitized solar cells | 6 |
| 1.4 Cerium doped TiO ₂ thin films | 8 |
| 1.4.1 Titanium Dioxide (TiO ₂) | 8. |
| 1.4.2 Cerium oxide (CeO ₂) | 10 |
| 1.5 Objectives | 11 |
| 1.6 Outline of Thesis | 11 |
| Chapter 2 | 13-17 |
| Literature Survey | |
| 2.1 Introduction | 13 |
| 2.2 Literature survey | 13 |
| 2.3 Conclusion | 17 |
| Chapter 3 | |

Experimental

| 3.1 Introduction | 18 |
|---|-------|
| 3.2 Methods for synthesis of nano-materials and films | 18 |
| 3.3 Materials | 20 |
| 3.4 Synthesis Procedure | 20 |
| 3.4.1 Preparation of TiO_2 thin films | 20 |
| 3.4.2 Preparation of Ce doped TiO_2 thin films | 21 |
| 3.5 Conclusion | 23 |
| Chapter 4 | 24-32 |
| Characterization techniques | |
| 4.1 Introduction | 24 |
| 4.2 Characterization techniques | 24 |
| 4.2.1 X-Ray Diffraction (XRD) | 24 |
| 4.2.2 Fourier transform Infrared Spectroscopy | 27 |
| 4.2.3 Photoluminescence (PL) spectroscopy | 28 |
| 4.2.4 UV-vis. UV-vis diffuse reflectance spectra (UV-DRS) | 30 |
| 4.2.5 Cyclic Voltammetry | 30 |
| 4.3 Conclusions | 32 |
| Chapter 5 | 33-58 |
| Results and Discussion | |
| 5.1 Introduction | 33 |
| 5.2 Characterization | 33 |

| 5.2.1 X-Ray Diffraction (XRD) | 33 |
|--|---------|
| 5.2.2 Fourier transform Infrared spectroscopy (FTIR) | 35 |
| 5.2.3 Photoluminescence (PL) Spectroscopy | 37 |
| 5.2.4 UV-vis diffuse reflectance spectra (UV-DRS) | 37 |
| 5.2.5 Cyclic voltammetry | 41 |
| 5.2.5.1 Cyclic voltammetry in dark conditions (Set up I) | 41 |
| 5.2.5.2Cyclic voltammetry in visible light (set up II) | 47 |
| 5.2.5.3 Variation of peak current with scan rate | 52 |
| 5.2.5.3.1 Peak current (Charging current) of cyclic voltammetry scan | |
| in dark condition | 52 |
| 5.2.5.3.2 Peak current (charging current) of cyclic voltammetry | scan in |
| visible light | 53 |
| 5.2.5.4Charge storage (surface charge density, $q (C/cm^2)$) | 54 |
| 5.2.5.4.1Charge storage in thin films in dark conditions | 54 |
| 5.2.5.4.2Charge storage in thin films under visible light | 55 |
| 5.2.5.5 Capacitance (C, µF) | 56 |
| 5.2.5.5.1 Variation of capacitance with scan rate in dark | 56 |
| 5.2.5.5.2 Variation of capacitance with scan rate in visible light | 57 |
| 5.3 Conclusion | 58 |
| Chapter 6 | 59-60 |
| Conclusion | |
| 6.1 Conclusion | 59 |
| References | 61-64 |

List of Figures

| Figure 1.1 Schematic representation of the dye-sensitized solar cell | 5 |
|---|----|
| Figure 1.2 Structure of (a) anatase (b) rutile and (c) brookite | 9 |
| Figure 3.1 Flow diagram of typical sol gel process | 19 |
| Figure 3.2 Preparation steps of TiO ₂ Film | 22 |
| Figure 3.3 Preparation steps of Ce doped TiO ₂ Films | 23 |
| Figure 4.1 Diffraction of the X-ray from consecutive layers of atom in crystal | 25 |
| Figure 4.2 Depiction of the mechanism of production of PL spectra | 29 |
| Figure 5.1 XRD of pure and doped TiO_2 thin films | 34 |
| Figure 5.2 FTIR spectrums of pure and doped TiO_2 thin films | 36 |
| Figure 5.3 PL Spectra of thin films at an excitation wavelength of 320nm | 38 |
| Figure 5.4 UV-DRS spectra of the prepared thin films | 39 |
| Figure 5.5 Optical band gap of the synthesized thin films | 40 |
| Figure 5.6 Cyclic Voltammetry of 0.00Ce doped TiO_2 under dark | 42 |
| Figure 5.7 Cyclic Voltammetry of 0.05Ce doped TiO_2 under dark | 43 |
| Figure 5.8 Cyclic Voltammetry of 0.20Ce doped TiO ₂ under dark | 44 |
| Figure 5.9 Cyclic Voltammetry of 0.50Ce doped TiO_2 under dark | 45 |
| Figure 5.10 Cyclic Voltammetry of 1.00Ce doped TiO_2 under dark | 46 |
| Figure 5.11 Cyclic Voltammetry of 0.00Ce doped TiO ₂ under visible light | 47 |
| Figure 5.12 Cyclic Voltammetry of 0.05Ce doped TiO ₂ under visible light | 48 |

| Figure 5.13 Cyclic Voltammetry of 0.20Ce doped TiO_2 under visible light | 49 |
|---|----|
| Figure 5.14 Cyclic Voltammetry of 0.50Ce doped TiO_2 under visible light | 50 |
| Figure 5.15 Cyclic Voltammetry of 1.00Ce doped TiO ₂ under visible light | 51 |
| Figure 5.16 Peak current v/s square root of scan rate | 53 |
| Figure 5.17 Peak current v/s square root of scan rate (visible light) | 54 |
| Figure 5.18 Variation of charge storage with scan rate in dark | 55 |
| Figure 5.19 Variation of charge storage with scan rate under visible light | 56 |
| Figure 5.20 Variation of Capacitance with scan rate in dark | 57 |
| Figure 5.21 Variation of Capacitance with scan rate in visble light | 58 |
| | |

List of Tables

•

| Table 5.1: Crystalline size of Ce-doped TiO ₂ thin films | 35 |
|--|----|
| Table 5.2: Band gaps of Ce doped TiO_2 thin films | 41 |
| Table 5.3 Characteristics of 0.00Ce doped film under dark conditions | 42 |
| Table 5.4 Characteristics of 0.05 Ce film under dark conditions | 43 |
| Table 5.5 Characteristics of 0.20 Ce film under dark conditions | 44 |
| Table 5.6 Characteristics of 0.50 Ce film under dark conditions | 45 |
| Table 5.7 Characteristics of 1.00 Ce film under dark conditions | 46 |
| Table 5.8 Characteristics of 0.00 Ce film under visible light | 47 |
| Table 5.9 Characteristics of 0.05 Ce film under visible light | 48 |
| Table 5.10Characteristics of 0.20 Ce film under visible light | 49 |
| Table 5.11 Characteristics of 0.50 Ce film under visible light | 50 |
| Table 5.12 Characteristics of 1.00 Ce film under visible light | 51 |